# NSN 5962-01-420-4639

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# **Body Length:**

Between 0.441 inches and 0.460 inches

# Body Width:

Between 0.442 inches and 0.460 inches

# **Body Height:**

Between 0.060 inches and 0.100 inches

# **Maximum Power Dissipation Rating:**

1.2 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Pacer dawn

#### Features Provided:

Electrostatic sensitive and hermetically sealed and burn in and programmed and monolithic

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Leadless flat pack

# **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

22 input

# Criticality Code Justification:

Cbbl

# Case Outline Source And Designator:

C-4 mil-m-38510

# **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, programmed (pal c22v10-25)

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Memory Device Type:

Pal

### **Special Features:**

Altered item; made from device 5962-88670013a, microcircuit, memory, digital, cmos, one-time programmable, programmable array logic, monolithic silicon

# **Test Data Document:**

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

28 leadless

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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